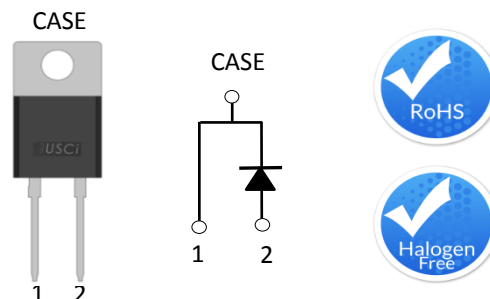


Description

United Silicon Carbide, Inc. offers the xR series of high performance SiC Schottky diodes. With zero reverse recovery charge and 175°C maximum junction temperature, USCi's diodes are ideally suited for high frequency and high efficiency power systems with minimum cooling requirements.



Part Number	Package	Marking
UJD06506TS	TO-220-2L	UJD06506TS

Features

- ♦ Positive temperature coefficient for safe operation and ease of paralleling
- ♦ 175°C maximum operating junction temperature
- ♦ Extremely fast switching not dependent on temperature
- ♦ Essentially no reverse or forward recovery
- ♦ Enhanced surge capability
- ♦ RoHS compliant

Typical Applications

- ♦ Power converters
- ♦ Industrial motor drives
- ♦ Switching-mode power supplies
- ♦ Power factor correction modules

Maximum Ratings

Parameter	Symbol	Test Conditions	Value	Units
DC blocking voltage	V_R		650	V
Repetitive peak reverse voltage, $T_J=25^\circ\text{C}$	V_{RRM}		650	V
Surge peak reverse voltage	V_{RSM}		650	V
Maximum DC forward current	I_F	$T_C = 153^\circ\text{C}$	6	A
Non-repetitive forward surge current sine halfwave	I_{FSM}	$T_C = 25^\circ\text{C}$, $t_p = 10\text{ms}$	45	A
		$T_C = 110^\circ\text{C}$, $t_p = 10\text{ms}$	36	
Repetitive forward surge current sine halfwave, $D=0.1$	I_{FRM}	$T_C = 25^\circ\text{C}$, $t_p = 10\text{ms}$	30.6	A
		$T_C = 110^\circ\text{C}$, $t_p = 10\text{ms}$	18	
Non-repetitive peak forward current	$I_{F,max}$	$T_C = 25^\circ\text{C}$, $t_p = 10\mu\text{s}$	310	A
		$T_C = 110^\circ\text{C}$, $t_p = 10\mu\text{s}$	279	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25^\circ\text{C}$, $L = 5\text{mH}$, $I_{pk}=4.25\text{A}$, $V_{DD}=100\text{V}$	50	mJ
Power dissipation	P_{Tot}	$T_C = 25^\circ\text{C}$	93	W
		$T_C = 153^\circ\text{C}$	13.7	
Maximum junction temperature	$T_{J,max}$		175	$^\circ\text{C}$
Operating and storage temperature	T_J , T_{STG}		-55 to 175	$^\circ\text{C}$
Soldering temperatures, wavesoldering only allowed at leads	T_{sold}	1.6mm from case for 10s	260	$^\circ\text{C}$

Electrical Characteristics

$T_J = +25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test Conditions	Value			Units
			Min	Typ	Max	
Forward voltage	V_F	$I_F = 6\text{A}, T_J = 25^\circ\text{C}$	-	1.5	1.7	V
		$I_F = 6\text{A}, T_J = 150^\circ\text{C}$	-	1.8	2.1	
		$I_F = 6\text{A}, T_J = 175^\circ\text{C}$	-	2	2.25	
Reverse current	I_R	$V_R = 650\text{V}, T_J = 25^\circ\text{C}$	-	15	200	μA
		$V_R = 650\text{V}, T_J = 175^\circ\text{C}$	-	30	640	
Total capacitive charge ⁽¹⁾	Q_C	$V_R = 400\text{V}$		12.7		nC
Total capacitance	C	$V_R = 1\text{V}, f = 1\text{MHz}$		179		pF
		$V_R = 300\text{V}, f = 1\text{MHz}$		21		
		$V_R = 600\text{V}, f = 1\text{MHz}$		18		
Capacitance stored energy	E_C	$V_R = 400\text{V}$		1.9		μJ

(1) See Figure 8, Q_C is independent on T_J , di_F/dt , and I_F as shown in the application note USCi_AN0011.

Thermal characteristics

Parameter	symbol	Test Conditions	Value			Units
			Min	Typ	Max	
Thermal resistance	$R_{\theta JC}$			1.2	1.6	$^\circ\text{C}/\text{W}$

Typical Performance

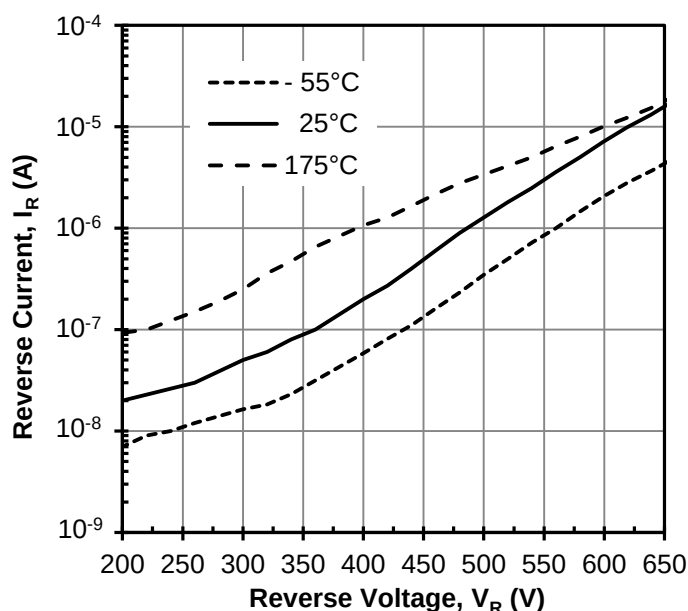


Figure 1 Typical reverse characteristics

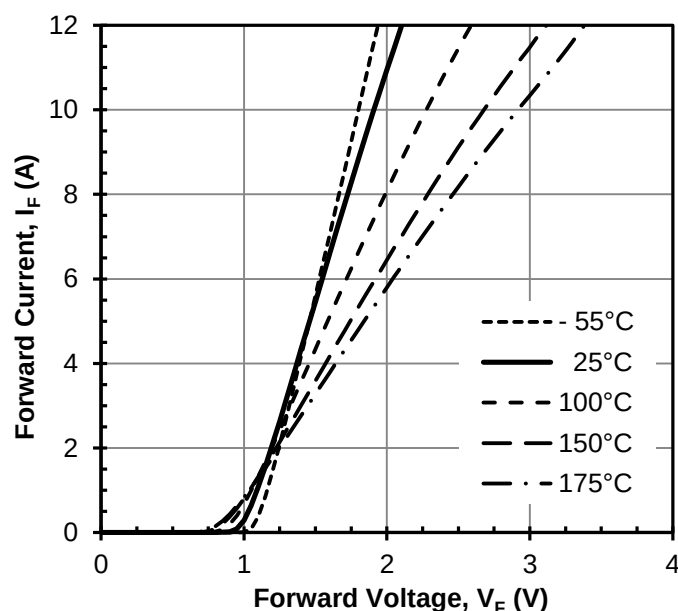


Figure 2 Typical forward characteristics

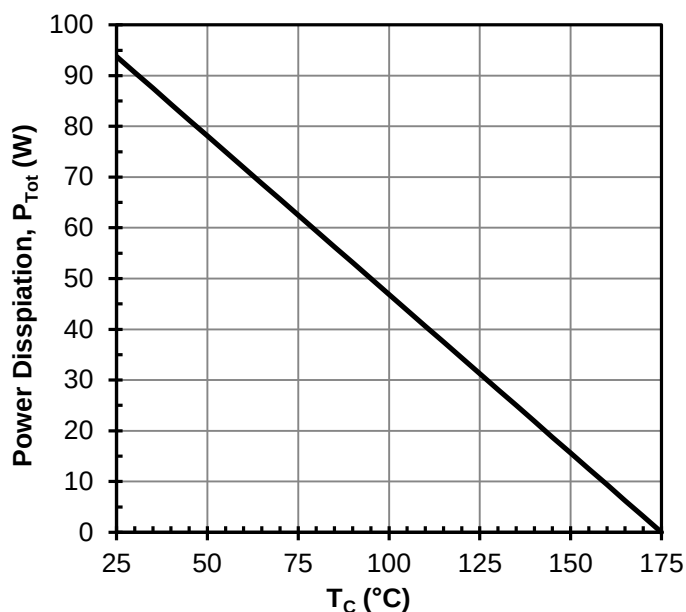


Figure 3 Power dissipation

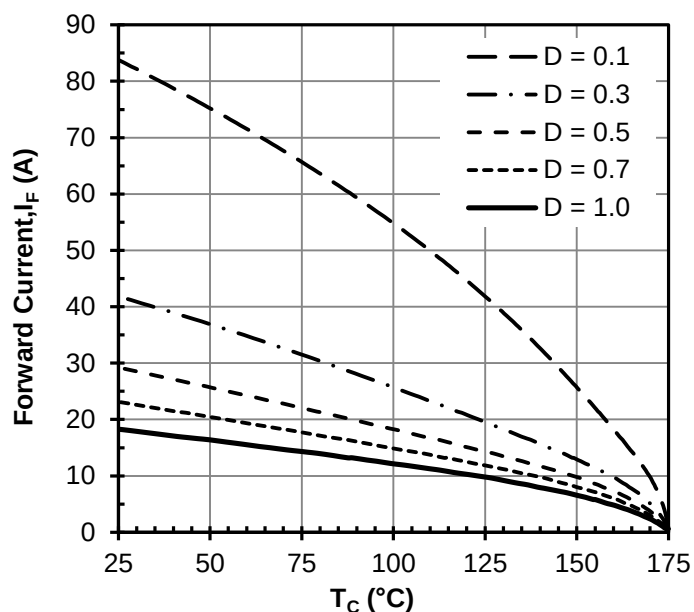


Figure 4 Diode forward current

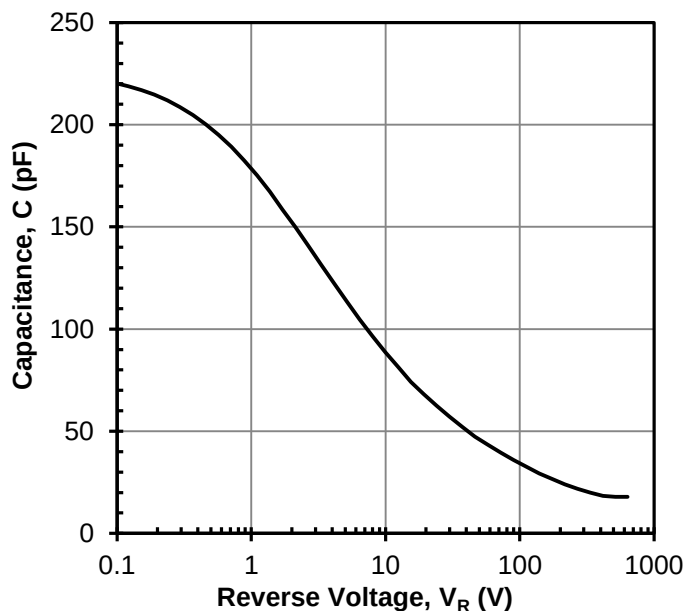


Figure 5 Capacitance vs. reverse voltage

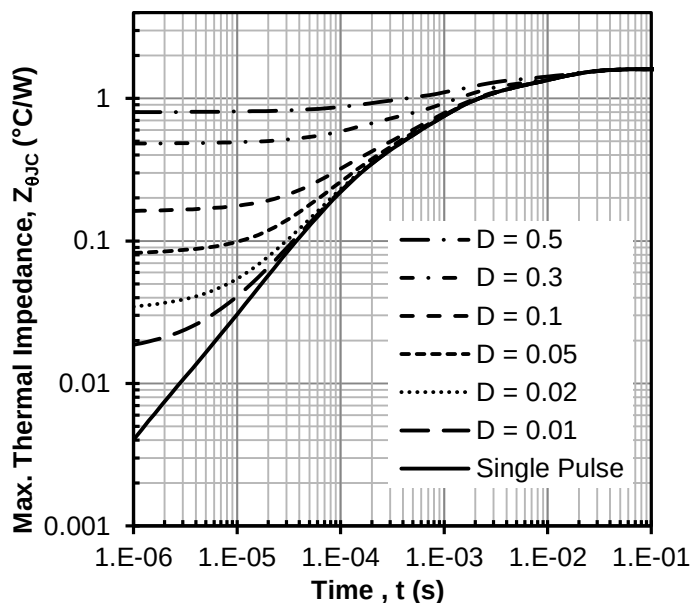


Figure 6 Maximum transient thermal impedance

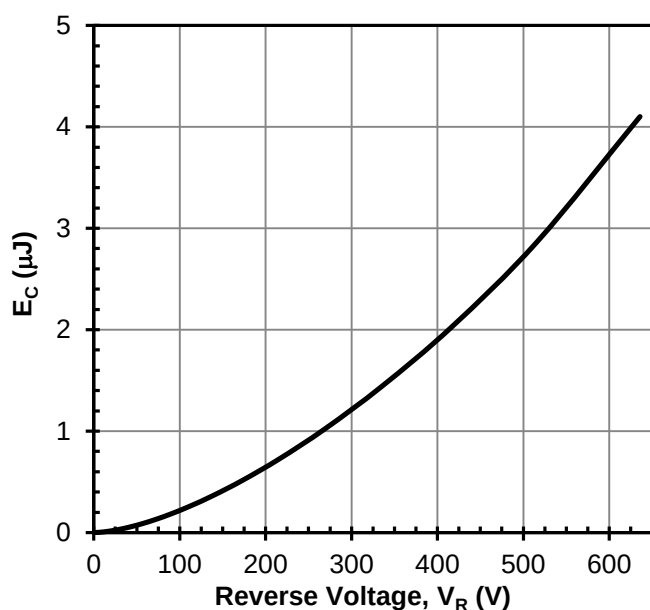


Figure 7 Typical capacitance stored energy vs. reverse voltage

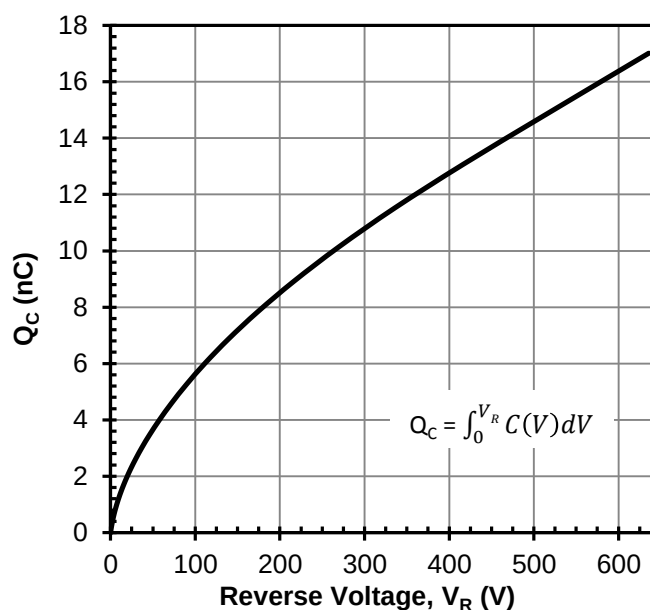


Figure 8 Typical capacitive charge vs. reverse voltage

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